

Field effect transistor sensor based on
Fe-Ni co-doped ZnO nanoparticles for the detection of hexahydropyridine chemical

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An effective chemical sensor based on field-effect transistor (FET) was fabricated for the detection of hexahydropyridine chemical. In this work, Fe-Ni co-doped zinc oxide ($Zn_{0.97}Fe_{0.01}Ni_{0.02}$) nanoparticles (NPs) were successfully synthesized by the hydrothermal technique. The morphological characterizations revealed the spherical and hexagonal NPs of average size of ~40-60 nm whereas, the EDS and XPS analysis confirmed the element compositions and doping of $Zn_{0.97}Fe_{0.01}Ni_{0.02}O$ NPs with Fe^{2+} and Ni^{2+} ions. Well-defined crystalline structure with typical wurtzite hexagonal phase of $Zn_{0.97}Fe_{0.01}Ni_{0.02}$ NPs was supported from the XRD analysis. The fabricated FET was used for the detection of different concentrations of hexahydropyridine chemical through an electrochemical analysis. $Zn_{0.97}Fe_{0.01}Ni_{0.02}O$ NPs modified FET-sensor displayed a high sensitivity of $\sim 62.28 \mu A \cdot \mu M^{-1} \cdot cm^{-2}$, a good detection limit of $\sim 79 \mu M$ and short response time of 10 s with correlation coefficient (R) of ~ 0.96405 .